LXA10T600

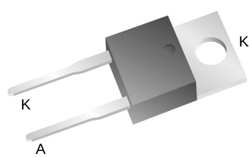
Qspeed™ Family

600 V, 10 A X-Series PFC Diode

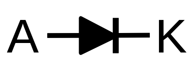
Product Summary

$I_{F(AVG)}$	10	A
V_{RRM}	600	V
Q_{RR} (Typ at 125 °C)	94	nC
I_{RRM} (Typ at 125 °C)	3.85	A
Softness t_B/t_A (Typ at 125 °C)	0.5	

Pin Assignment



TO-220AC



RoHS Compliant

Package uses Lead-free plating and Green mold compound.
Halogen free per IEC 61249-2-21.

General Description

This device has the lowest Q_{RR} of any 600 V silicon diode. Its recovery characteristics increase efficiency, reduce EMI and eliminate snubbers.

Applications

- Power Factor Correction (PFC) boost diode
- Motor drive circuits
- DC-AC inverters

Features

- Low Q_{RR}, low I_{RRM}, low t_{RR}
- High dI_F/dt capable (1000 A/μs)
- Soft recovery

Benefits

- Increases efficiency
  - Eliminates need for snubber circuits
  - Reduces EMI filter component size and count
- Enables extremely fast switching

Absolute Maximum Ratings

Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Symbol	Parameter	Conditions	Rating	Units
V_{RRM}	Peak repetitive reverse voltage		600	V
$I_{F(AVG)}$	Average forward current	T_J = 150 °C, T_C = 118 °C	10	A
I_{FSM}	Non-repetitive peak surge current	60 Hz, ½ cycle	70	A
I_{FSM}	Non-repetitive peak surge current	½ cycle of t = 28 μs Sinusoid, T_C = 25 °C	350	A
$T_{J(MAX)}$	Maximum junction temperature		150	°C
T_{STG}	Storage temperature		–55 to 150	°C
	Lead soldering temperature	Leads at 1.6 mm from case, 10 sec	300	°C
P_D	Power dissipation	T_C = 25 °C	89	W

Thermal Resistance

Symbol	Resistance from:	Conditions	Rating	Units
$R_{\theta JC}$	Junction to case	TO-220AC	1.4	°C/W

Electrical Specifications at T_J = 25 °C (unless otherwise specified)

Symbol	Parameter	Conditions		Min	Typ	Max	Units
DC Characteristics							
I_R	Reverse current	V_R = 600 V, T_J = 25 °C		-	-	250	μA
		V_R = 600 V, T_J = 125 °C		-	1.2	-	mA
V_F	Forward voltage	I_F = 10 A, T_J = 25 °C		-	2.4	3.0	V
		I_F = 10 A, T_J = 150 °C		-	2.1	-	V
C_J	Junction capacitance	V_R = 10 V, 1 MHz		-	51	-	pF
Dynamic Characteristics							
t_{RR}	Reverse recovery time	dI/dt = 200 A/μs V_R = 400 V, I_F = 10 A	T_J = 25 °C	-	23	-	ns
			T_J = 125 °C	-	35	-	ns
Q_{RR}	Reverse recovery charge	dI/dt = 200 A/μs V_R = 400 V, I_F = 10 A	T_J = 25 °C	-	36	54	nC
			T_J = 125 °C	-	94	-	nC
I_{RRM}	Maximum reverse recovery current	dI/dt = 200 A/μs V_R = 400 V, I_F = 10 A	T_J = 25 °C	-	2.35	3.2	A
			T_J = 125 °C	-	3.85	-	A
S	Softness factor = $\frac{t_B}{t_A}$	dI/dt = 200 A/μs V_R = 400 V, I_F = 10 A	T_J = 25 °C	-	0.75	-	
			T_J = 125 °C	-	0.5	-	

Note to component engineers: X-Series diodes employ Schottky technologies in their design and construction. Therefore, Component Engineers should plan their test setups to be similar to those for traditional Schottky test setups. (For additional details, see Application Note AN-300.)

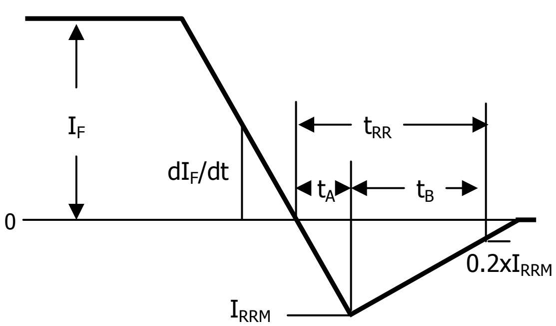


Figure 1. Reverse Recovery Definitions.

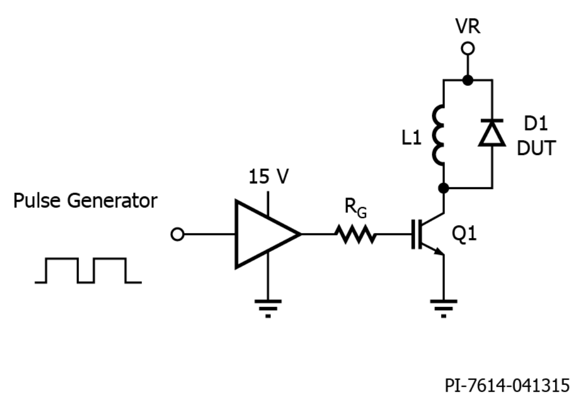


Figure 2. Reverse Recovery Test Circuit.

Electrical Specifications at T_J = 25 °C (unless otherwise specified)

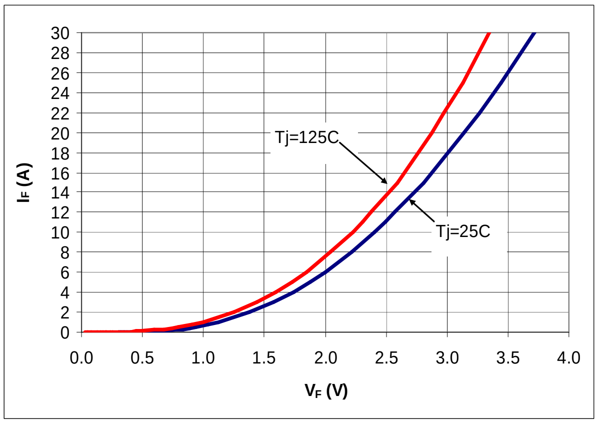


Figure 3. Typical I_F vs. V_F.

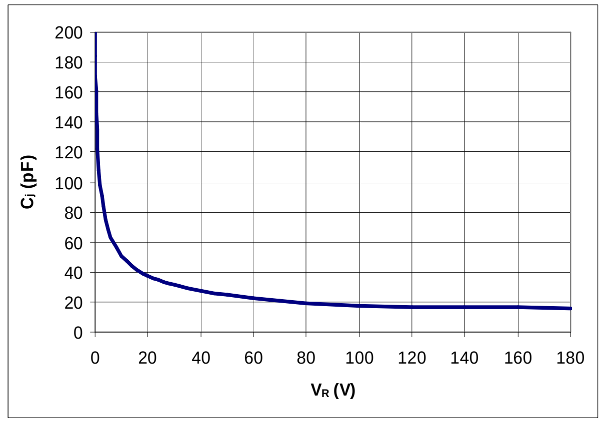


Figure 4. Typical C_J vs. V_R.

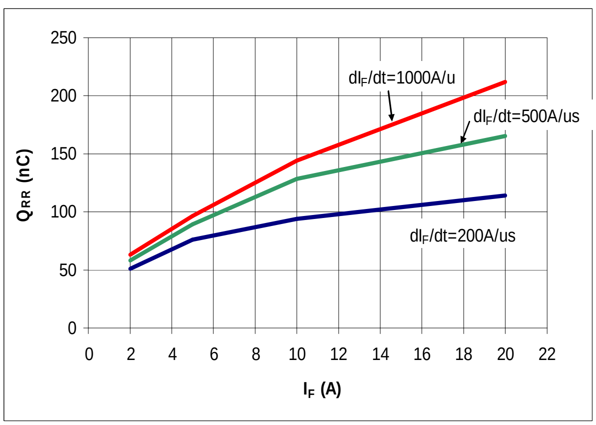


Figure 5. Typical Q_{RR} vs. I_F at T_J = 125 °.

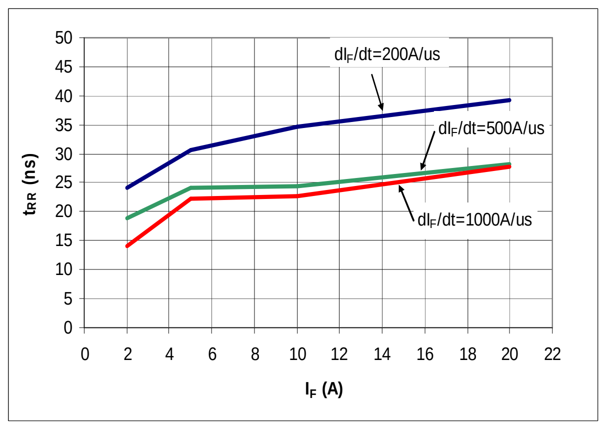


Figure 6. Typical t_{RR} vs. I_F at T_J = 125 °C.

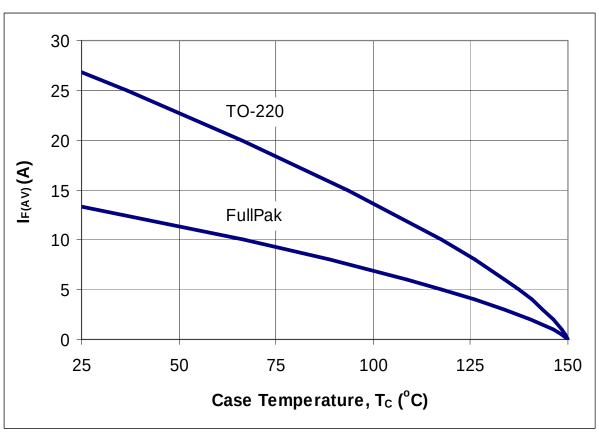


Figure 7. DC Current Derating Curve.

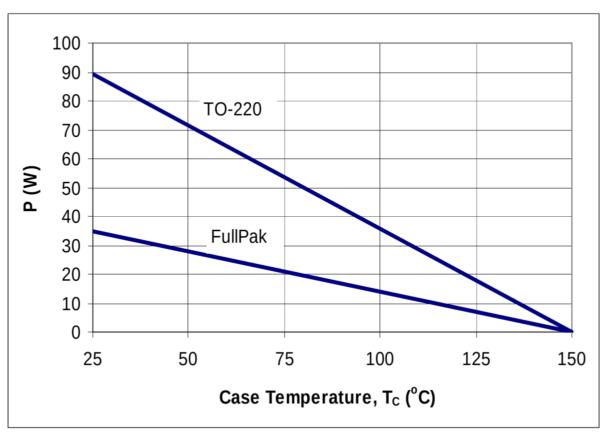


Figure 8. Power Derating Curve.

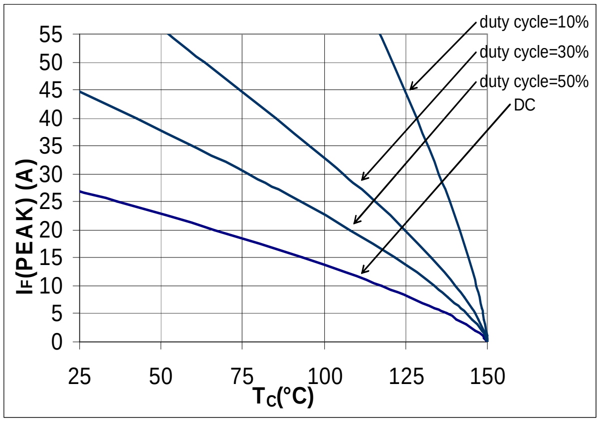


Figure 9. I_F(PEAK) vs. T_C, f = 70 kHz, TO-220.

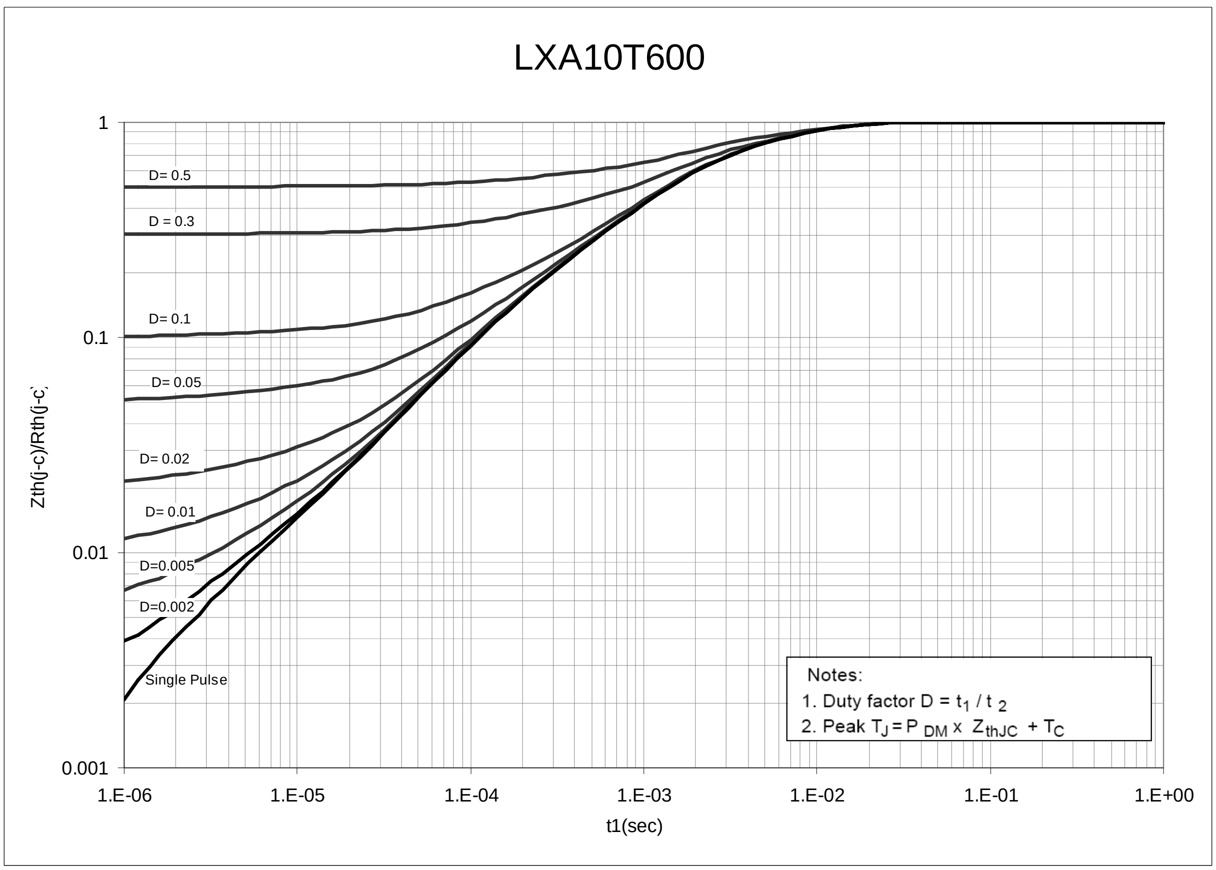
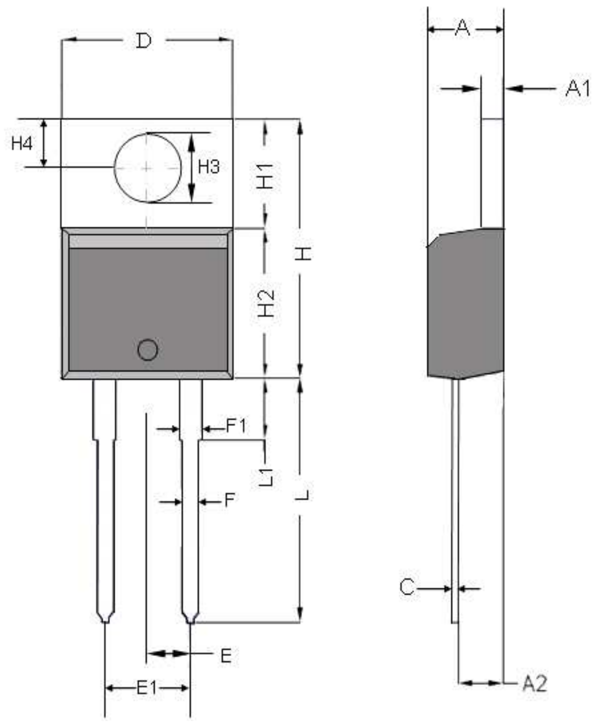


Figure 10. Normalized Maximum Transient Thermal Impedance, TO-220.

Dimensional Outline Drawings



	Millimeters	
Dim	**MIN**	**MAX**
A	4.32	4.70
A1	1.14	1.40
A2	2.03	2.79
C	0.34	0.610
D	9.65	10.67
E	2.49	2.59
E1	4.98	5.18
F	0.508	1.016
F1	1.14	1.78
H	14.71	16.51
H1	5.84	6.55
H2	8.51	9.25
H3	3.53	3.96
H4	2.54	3.05
L	12.70	14.22
L1	-	6.35

TO-220AC

Mechanical Mounting Method	Maximum Torque / Pressure specification
Screw through hole in package tab	1 Newton Meter (nm) or 8.8 inch-pounds (lb-in)
Clamp against package body	12.3 kilogram-force per square centimeter (kgf/cm^2) or 175 lbf/in^2

Soldering time and temperature: This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

Ordering Information

Part Number	Package	Packing
LXA10T600	TO-220	50 units/tube

The information contained in this document is subject to change without notice.

Revision	Notes	Date
1.0	Released by Qspeed.	06/10
1.1	Converted to Power Integrations Document.	01/11
1.1	Stop Point of t_{RR} error corrected due to typo in Figure 1.	11/13
1.2	Removed LXA10FP600 parts. Updated with new Brand Style.	01/16

For the latest updates, visit our website: www.power.com

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